# BCP68; BC868; BC68PA 20 V, 2 A NPN medium power transistors Rev. 8 – 18 October 2011

#### 1. Product profile

#### 1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Table 1.	Product overview

Type number <sup>[1]</sup>	Package	Package				
	NXP	JEITA	JEDEC			
BCP68	SOT223	SC-73	-	BCP69		
BC868	SOT89	SC-62	TO-243	BC869		
BC68PA	SOT1061	-	-	BC69PA		

[1] Valid for all available selection groups.

#### **1.2 Features and benefits**

- High current
- Two current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

#### **1.3 Applications**

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

#### 1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	20	V
I <sub>C</sub>	collector current		-	-	2	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	3	А



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Table 2.	Quick reference data continued					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h <sub>FE</sub>	DC current gain	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<mark>[1]</mark> 85	-	375	
	h <sub>FE</sub> selection -25	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<u>1</u> 160	-	375	

## 2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2, 4
3	emitter		1-
4	collector		3
SOT89			sym016
1	emitter		
2	collector		2 J
3	base		3
SOT1061			
1	base		2
2	emitter	3	3
3	collector		
		1   2     Transparent top view	sym021

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#### 3. Ordering information

Table 4. Ordering information						
Type number <sup>[1]</sup>	Package					
	Name	Description	Version			
BCP68	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BC868	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89			
BC68PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061			

[1] Valid for all available selection groups.

## 4. Marking

Table 5. Marking codes	
Type number	Marking code
BCP68	BCP68
BCP68-25	BCP68/25
BC868	CAC
BC868-25	CDC
BC68PA	AR
BC68-25PA	AS

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#### 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	32	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	20	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	2	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 \text{ ms}$	-	3	A
I <sub>B</sub>	base current		-	0.4	А
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms	-	0.4	A
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$			
	BCP68		<u>[1]</u> -	0.65	W
			[2] _	1.00	W
			[3] _	1.35	W
	BC868		<u>[1]</u> _	0.50	W
			[2] _	0.95	W
			<u>[3]</u>	1.35	W
	BC68PA		<u>[1]</u> _	0.42	W
			[2] _	0.83	W
			<u>[3]</u> _	1.10	W
			<u>[4]</u> _	0.81	W
			<u>[5]</u> _	1.65	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.



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#### 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
-				IVIIII	тур	IVIAX	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air					
	BCP68		<u>[1]</u>	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
	BC868		[1]	-	-	250	K/W
			[2]	-	-	132	K/W
			[3]	-	-	93	K/W
	BC68PA		[1]	-	-	298	K/W
			[2]	-	-	151	K/W
			[3]	-	-	114	K/W
			[4]	-	-	154	K/W
			[5]	-	-	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point						
	BCP68			-	-	16	K/W
	BC868			-	-	16	K/W
	BC68PA			-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.













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#### 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 25 \text{ V}; \text{ I}_{E} = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 25 \text{ V}; \text{ I}_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 10 V					
		I <sub>C</sub> = 5 mA		50	-	-	
	DC current gain	$V_{CE} = 1 V$					
		I <sub>C</sub> = 500 mA	[1]	85	-	375	
		$I_{\rm C} = 1  \rm A$	[1]	60	-	-	
		I <sub>C</sub> = 2 A	[1]	40	-	-	
	DC current gain	$V_{CE} = 1 V$					
	h <sub>FE</sub> selection -25	I <sub>C</sub> = 500 mA	[1]	160	-	375	
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 1 A; I <sub>B</sub> = 100 mA	[1]	-	-	0.5	V
	saturation voltage	$I_{C} = 2 \text{ A}; I_{B} = 200 \text{ mA}$	[1]	-	-	0.6	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE}$ = 10 V; $I_{C}$ = 5 mA	<u>[1]</u>	-	-	0.7	V
		$V_{CE} = 1 V; I_{C} = 1 A$	[1]	-	-	1	V
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V};  \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$		-	22	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz		40	170	-	MHz

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta = 0.02$ .



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#### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

#### 9. Package outline



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#### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

BCP68 SOT223 8 mm pitch, 12 mm tape and reel -11513	Туре	Package	Description	Description		Packing quantity		
BC868         SOT89         8 mm pitch, 12 mm tape and reel; T1         [3]         -115         -         -13           8 mm pitch, 12 mm tape and reel; T3         [4]         -146         -         -	number <sup>[2]</sup>				1000	3000	4000	
8 mm pitch, 12 mm tape and reel; T3 [4] -146	BCP68	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135	
- · · · · · · · · · · · · · · · · · · ·	BC868	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135	
BC68PA SOT1061 4 mm pitch, 8 mm tape and reel115 -			8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-	
	BC68PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-	

[1] For further information and the availability of packing methods, see Section 14.

[2] Valid for all available selection groups.

[3] T1: normal taping

[4] T3: 90° rotated taping

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#### 11. Soldering



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#### 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP68_BC868_BC68PA v.8	20111018	Product data sheet	-	BC868 v.7 BCP68 v.4		
Modifications:		of this document has be of NXP Semiconductors.	en redesigned to comp	bly with the new identity		
	<ul> <li>Legal texts</li> </ul>	have been adapted to th	e new company name	where appropriate.		
	<ul> <li>Type numb</li> </ul>	er BC68PA added				
	Section 1 "	Product profile": updated				
	Section 2 "	Pinning information": upd	ated			
	<ul> <li>Section 3 "</li> </ul>	Ordering information": up	dated			
	<ul> <li>Section 4 "</li> </ul>	Marking": updated				
	<ul> <li>Section 8 "</li> </ul>	Test information": added				
	<ul> <li><u>Section 9 "Package outline"</u>: updated</li> </ul>					
	<ul> <li><u>Section 10 "Packing information"</u>: added</li> </ul>					
	Section 11	"Soldering": added				
	• <u>Table 6, 7</u> a	and <u>8</u> : updated according	to latest measuremen	nts		
	<ul> <li>Figure 1, 2</li> </ul>	, <u>6</u> , <u>8</u> , <u>15</u> to <u>18</u> : updated				
	• Figure 3, 4	, <u>5</u> , <u>7</u> , <u>9</u> , <u>10</u> to <u>13</u> : added				
BC868 v.7	20041108	Product specification	-	BC868 v.6		
BC868 v.6	20031202	Product specification	-	BC868 v.5		
BC868 v.5	19990408	Product specification	-	BC868 v.4		
BC868 v.4	19980716	Product specification	-	BC868_CNV v.3		
BC868_CNV v.3	19970319	Product specification	-	BC868_CNV v.2		
BC868_CNV v.2	19970307	Product specification	-	-		
BCP68 v.4	20031125	Product specification	-	BCP68 v.3		
BCP68 v.3	19990408	Product specification	-	BCP68_CNV v.2		
BCP68_CNV v.2	19970409	Product specification				

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#### 13. Legal information

#### 13.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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